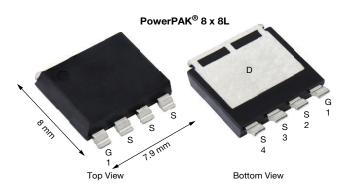
AUTOMOTIVE

Vishay Siliconix

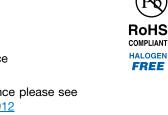
# Automotive N-Channel 40 V (D-S) 175 °C MOSFET

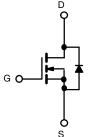


PRODUCT SUMMARY					
V <sub>DS</sub> (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.00053				
I <sub>D</sub> (A)	701				
Configuration	Single				

#### **FEATURES**

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>q</sub> and UIS tested
- Thin 1.6 mm package
- · Very low thermal resistance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK 8 x 8L
Lead (Pb)-free and halogen-free	SQJQ140E (for detailed order number please see <a href="https://www.vishay.com/doc?79776">www.vishay.com/doc?79776</a> )

ABSOLUTE MAXIMUM RATING	(1) = 25 O, unless		1		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		$V_{DS}$	40	V	
Gate-source voltage	urce voltage		± 20		
Continuous drain current	T <sub>C</sub> = 25 °C	1	701		
	T <sub>C</sub> = 125 °C	I <sub>D</sub>	405		
Continuous source current (diode conduction)		I <sub>S</sub>	545	Α	
ulsed drain current <sup>a</sup>		I <sub>DM</sub>	1820		
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	79		
Single pulse avalanche energy	L = 0.1 min	E <sub>AS</sub>	312	mJ	
Maximum power dissipation	T <sub>C</sub> = 25 °C	D	600	W	
	T <sub>C</sub> = 125 °C	$P_{D}$	200	VV	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering recommendations (peak temperature) c		-	260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount b	$R_{thJA}$	44	°C/W
Junction-to-case (drain)		$R_{thJC}$	0.25	C/VV

#### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %
- b. When mounted on 1" square PCB (FR4 material)

S20-0985-Rev. A, 28-Dec-2020

c. See solder profile (<a href="www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static	1			l	•		
Drain-source breakdown voltage	$V_{DS}$	$V_{GS} = 0$ , $I_D = 250 \mu A$		40	-	-	V
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	· V <sub>GS</sub> , I <sub>D</sub> = 250 μA	2.3	2.7	3.3	V
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V	-	-	1	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 125 °C	-	-	50	μΑ
		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 175 °C	-	-	150	
On-state drain current a	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	$V_{DS} \ge 5 V$	100	-	-	Α
	, ,	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 20 A	-	0.00044	0.00053	Ω
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 20 A, T <sub>J</sub> = 125 °C	-	-	0.00092	
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 20 A, T <sub>J</sub> = 175 °C	-	-	0.0013	
Forward transconductance b	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 80 A		-	160	-	S
Dynamic <sup>b</sup>							
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = 25 V, f = 1 MHz	-	12 140	17 000	pF
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$		-	4740	6636	
Reverse transfer capacitance	C <sub>rss</sub>			-	308	432	
Total gate charge <sup>c</sup>	$Q_g$			-	192	288	
Gate-source charge c	$Q_{gs}$	V <sub>GS</sub> = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 40 \text{ A}$	-	55	-	nC
Gate-drain charge <sup>c</sup>	$Q_{gd}$			-	41	-	
Gate resistance	$R_g$	f = 1 MHz		0.8	1.6	2.4	Ω
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	26	39	
Rise time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 20 \text{ V}, \text{ R}_{L} = 0.5 \Omega$ $I_{D} \cong 40 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		-	78	117	ns
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>			-	62	93	
Fall time <sup>c</sup>	t <sub>f</sub>			-	32	48	
Source-Drain Diode Ratings and Char	racteristics <sup>b</sup>						
Reverse recovery time	t <sub>rr</sub>	V <sub>DD</sub> = 32 V, I <sub>FM</sub> = 20 A, di/dt = 100 A/μs		-	94	188	ns
Reverse recovery charge	Q <sub>rr</sub>			-	177	354	nC
Reverse recovery current	I <sub>RM</sub>			-	-3.2	-	Α
Pulsed current a	I <sub>SM</sub>			_	-	1600	Α
. 4.004 04	Olvi						

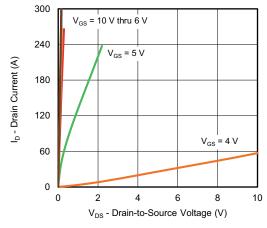
### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

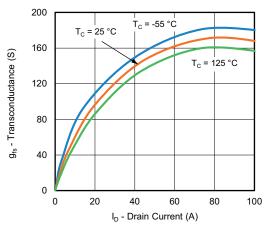
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



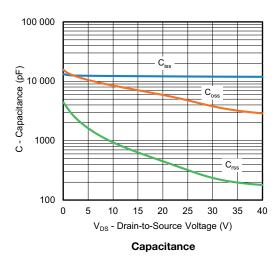
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

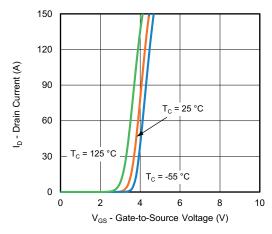


### **Output Characteristics**

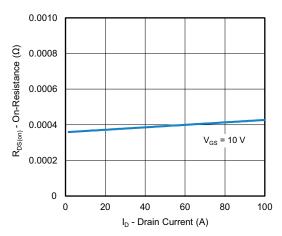


Transconductance

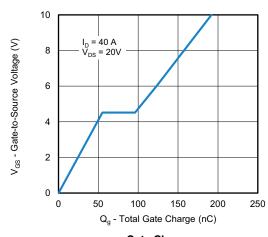




**Transfer Characteristics** 



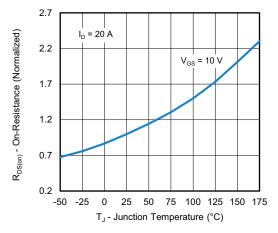
**On-Resistance vs. Drain Current** 



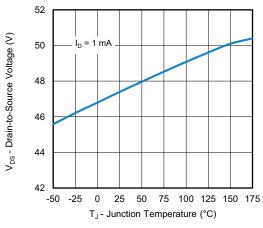
Gate Charge



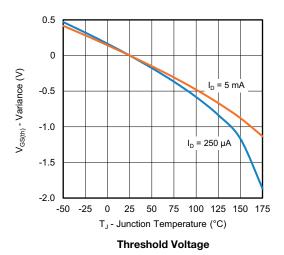
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

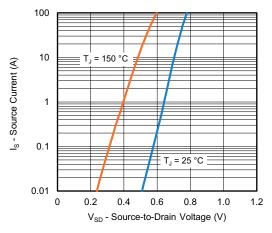


On-Resistance vs. Junction Temperature

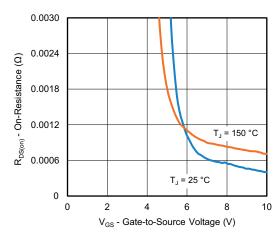


Drain Source Breakdown vs. Junction Temperature

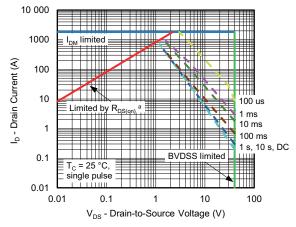




**Source Drain Diode Forward Voltage** 



On-Resistance vs. Gate-to-Source Voltage



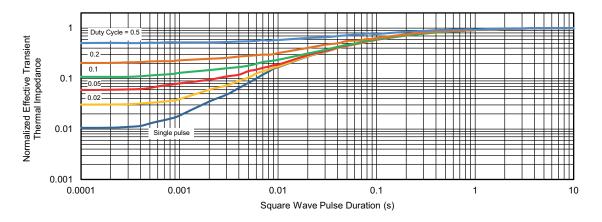
Safe Operating Area

#### Note

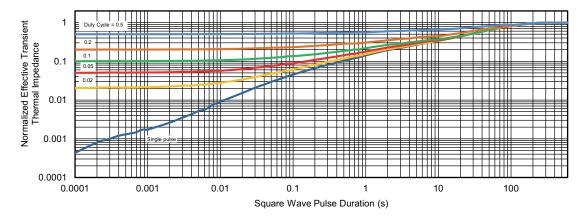
a. V<sub>GS</sub> > minimum V<sub>GS</sub> at which R<sub>DS(on)</sub> is specified



### THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



#### Normalized Thermal Transient Impedance, Junction-to-Ambient



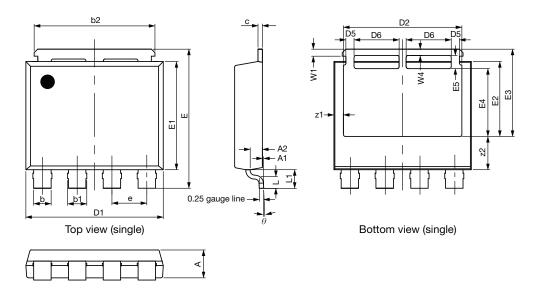
Normalized Thermal Transient Impedance, Junction-to-Case

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www.vishay.com

# PowerPAK® 8 x 8L BWL Case Outline 2



MAX.
0.067
0.005
0.030
0.043
0.046
0.277
0.012
0.315
0.272
0.022
0.106
0.080
0.319
0.249
0.174
0.202
0.157
0.033
0.030
0.045
0.020
0.017
0.026
0.079
5°

ECN: S19-0643-Rev. B, 05-Aug-2019

DWG: 6073

#### Note

Millimeter will govern

Revison: 05-Aug-2019 Document Number: 79736



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